PARED BY: DATE: Jun /16/99 L U e da ROVED BY: DATE: Jun /16/99 Fulzase DEVICE SP	SHARP ELECTRONIC COMPONENTS GROUP SHARP CORPORATION SPECIFICATION PECIFICATION FOR Light Emitting Diode GL5ZS44		DG996041 Jun/16/99 10 pages ATIVE DIVISION: nic Devices Division
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and the instructions included in the (Precautions) (1) This products is designed * OA equipment * A * Telecommunication * Tooling machines If the use of the product (2) or (3), please be sure (2) Appropriate measures, so the safety design of the cand safety when this processafety in function and professions * Transportation contractions * Traffic signals * O	ol and safety equipment (aircraft, train, autom Gas leakage sensor breakers * Rescue and se	ent ent listed in paragra bective paragraphs onsidering to ensure reliability reliability and	iphs
and safety in function an * Space equipment	oduct for equipment which require extremely l		
(4) Please contact and consu	alt with a Sharp sales representative if there are of the above three paragraphs.	e any questions	
3. Please contact and consult with a S	Sharp sales representative for any questions ab	out this product.	

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CUSTOMER'S APPROVAL	DATE: Jun//8/1771 PRESENTED BY: h. (gloh)
	M.Katoh,
DATE:	Department General Manager of
	Engineering Dept.,III
	Opto-Electronic Devices Division
BY:	Electronic Components Group
	SHARP CORPORATION

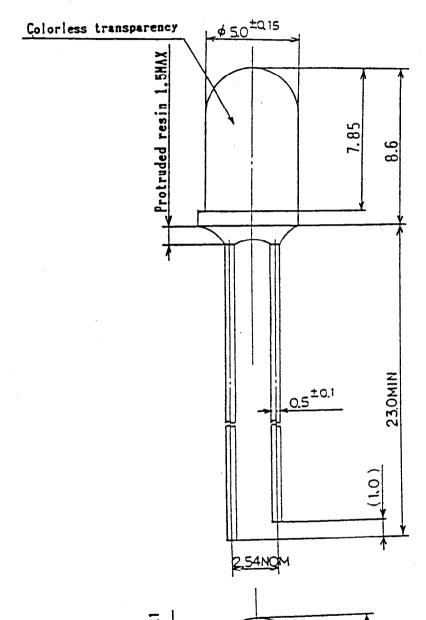
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GL5ZS44 Specification

1. Application This specification applies to the light emitting diode device Model No. GL5ZS44. [AlGaInP (dicing or scribe/brake type) Sunset-orange LED device]
2. Outline dimensions and pin connections ······Refer to the attached sheet Page 2.
3. Ratings and characteristics
4. Reliability ······Refer to the attached sheet Page 5. 4-1. Test items and test conditions 4-2. Measurement items and Failure judgement criteria
 5. Incoming inspection
6. Supplement ······Refer to the attached sheet Page 7~8. 6-1. Packing 6-2. Luminous intensity rank 6-3. Dominant wavelength rank 6-4. Environment
7. Precautions for use ······ Refer to the attached sheet Page 9~10. 7-1. Lead forming method 7-2. Notice of installation 7-3. Soldering Conditions 7-4. For cleaning

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2. Outline dimensions and pin connections



Pin connections

- ①. Anode
- 2. Cathode

(Note) Unspecified tol. to be ± 0.2 mm

(Note) Cold rolled steel leads are plated with but the tie-bar cut portions have no plating do not solder this part of the product.

Unit Material		Finish	Drawing No.	
	Lead: (Fe) Cold rolled steel			
mm	Package: Epoxy resin	Lead: Sn plated or wave soldering	51106022	

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3. Ratings and characteristics

3-1. Absolute maximum ratings (T			Γa=25°C)			
Parameter		Symbol	Value		Unit	
Power dissipation	1	P	P 130		mW	
Continuous forwa	ard current	I _F	50		mA	
Peak forward cur	rent(Note 1)	I _{FM}	100		mA	
Derating factor	DC	•		0.67		mA/C
	Pulse	-		1.33		mA/C
Reverse voltage		V_R		5		V
Operating temper	ature	Topr	-40 ~ 85		°C	
Storage temperati	ure	Tstg -40 ~ 100		°C		
Soldering temper	ature(Note 2)	Tsol	260 (within 5 seconds)		°C	

(Note 1) Duty ratio=1/10, Pulse width=0.1ms

(Note 2) At the position of 1.6mm from the bottom resin package

3-2. Electro-optical characteristics

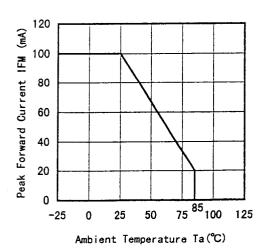
(Ta=25°C)

Parameter Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F		-	2.1	2.6	V
Luminous intensity (Note 3)	Iv		1144	4200	_	mcd
Peak emission wavelength	λp	IF=20mA		609	-	nm
Dominant wavelength	λd		_	605	_	nm
Spectrum radiation bandwidth	Δλ		_	15	_	nm
Reverse current	I_R	VR=4V		_	100	μΑ
Terminal capacitance	Ct	V=0V,f=1MHz	_	60		pF
Viewing Angle	2 0 1/2	IF=20mA	<u> </u>	15	_	deg.

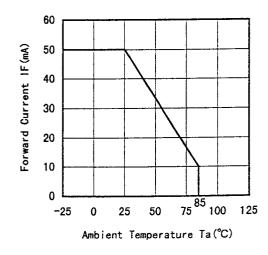
(Note 3) Refer to the suplement item 6. regarding the standard of rank classification.

3-3. Derating Curve

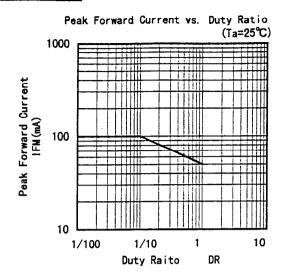
Peak Forward Current Derating Curve



Forward Current Derating Curve



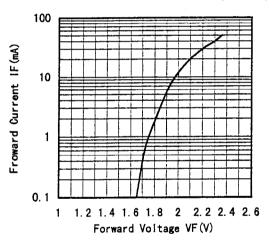
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3-4. Characteristics Diagram(typ) (Note 1)

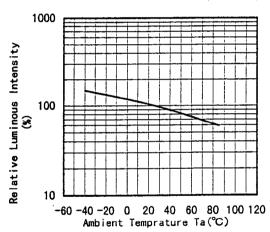
Forward Current vs. Forward Voltage

(Ta=25°C)

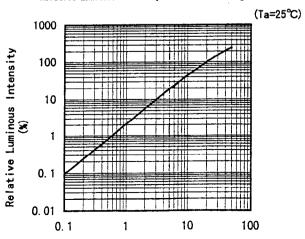


Relative Luminous Intensity vs. Ambient Temperature

(1F=20mA)



Relative Luminous Intensity vs. Froward Voltage



Forward Current IF (mA)

(Note 1) Above characteristic data are typical data and not a guarantteed data.

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Confidence level: 90%

n=22, C=0

n=22, C=0

10

10

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4. Reliability

The reliability of products shall be satisfied with items listed below.

4-1. Test items and test conditions

Test items	Test conditions	Samples (n) Defective (C)	LTPD (%)
Solderability	230 \pm 5 $^{\circ}$ C, 5s Prior disposition : Dip in rosin flux	n=11, C=0	20
Soldering temperature	260±5℃, 5s	n=11, C=0	20
Mechanical shock	15 000m/s ² , 0.5ms, 3times / ±X,±Y,±Z direction	n=11, C=0	20
Variable frequency vibration	200m/s ² , 100 to 2 000 to 100Hz/sweep for 4min. ,4times/±X,±Y,±Z direction	n=11, C=0	20
Terminal strength (Tension)	Weight:10N, 5s/each terminal	n=11, C=0	20
Terminal strength (Bending)	Weight:5N, $0^{\circ} \rightarrow 90^{\circ} \rightarrow 0^{\circ} \rightarrow -90^{\circ} \rightarrow 0^{\circ}$ /each terminal	n=11, C=0	20
Temperature cycling	-40°C(30min)∼+100°C(30min),30 cycles	n=22, C=0	10
High temp. and high humidity storage	Ta=+60°C, 90%RH, t=1000h	n=22, C=0	10
High temperature storage	Ta=100°C, t=1000h	n=22, C=0	10

4-2. Measurement items and Failure judgement criteria *1

Low temperature storage Ta=-40°C, t=1000h

Operation life

Measurement	Symbol	Failure judgement criteria *2
Forward voltage	V_{F}	V _F > U.S.L. × 1.2
Reverse current	I_{R}	$I_R > U.S.L. \times 2.0$
Luminous intensity	Iv	Iv > The first stage value \times 2.0 or The first stage value \times 0.5 > Iv

 $\ensuremath{\ensuremath{\%}}$ Solderability : Solder shall be adhere at the area of 95% or more of dipped portion.

Ta=25 $^{\circ}$ C, I_FMAX, t=1000h *3

- % Terminal strength: Package is not destroyed, and terminal is not slack.
- *1: Measuring condition is in accordance with specification.
- *2: U.S.L. is shown by Upper Specification Limit.
- *3: I_F MAX.is shown by forward current of absolute maximum ratings.

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5. Incoming inspection

5-1. Applied standard: ISO 2859-1

5-2. Sampling method and level : A single sampling plan, normal inspection level $\,\mathrm{I\hspace{-.1em}I}$

: AQL Major defect : 0.065% Minor defect : 0.4%

5-3. Test items, judgement criteria and classifica of defect

No.	Test items	judgement criteria	classifica of defect
1	Disconnection	Not emit light	
2	Position of Cutting off rim	Different from dimension	Major defect
3	Reverse terminal	Different from dimension	
4	Outline dimensions	Not satisfy outline specification	
5	Characteristics	Over the limit value of specification at V_F , I_R , and I_V	
6	Cut off the rim	Exceed -0.2mm	
7	Foreign substance	White point: Exceed ϕ 0.3mm (on top view) Black point: Exceed ϕ 0.3mm (on top view) String form: Exceed 3.0mm (on top view)	
8	Scratch	Exceed ϕ 0.3mm or 0.1mm × 1.0mm (on top view)	Minor defect
9	Void	Exceed ϕ 0.3mm (on top view)	
10	Uneven density of material for scattering	Extremely lineven density	
11	Unbalanced center	Exceed ±0.25mm from package center	
12	Burr	Exceed +0.2mm againstprovided dimension	
13	Insertion position of terminal	Insertion position of terminal	

5-4. Test items the surface is be applied for flat type, judgement criteria and classifica of defect

No.	Test items	judgement criteria	classifica of defect
14	Chapped the surface	The surface chapped is striking for see the lamp top	Minor defect
15	Hollow the surface	The surface hollow is striking for see the lamp top	

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6. Supplement

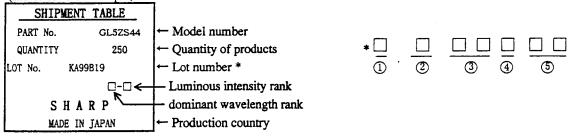
6-1. Packing

6-1-1. Inner package

Put 250pcs the same luminous intensity rank products into pack and put following label by pack.

Product weight: 0.28g (One Product, Typ.)

(Indication label sample)



- (1) Production plant code(to be indicated alphabetically)
- ② Support code
- (3) Year of production(the last two figures of the year)
- 4 Month of production (to be indicated alphabetically with January corresponding to A)
- 5 Date of production(01~31)

6-1-2. Outer package

Put 8 packs (the same luminous intensity rank) into outer package. (approximately 670g per one outer package)

6-1-3. Outer package out line dimension

Width: 140mm, Depth: 225mm, Hight: 90mm

6-2.Luminous intensity rank (Note 1)

(Ta=25℃)

Rank	Lum	inous int	ensity	Unit	Condition
N	1144	~	2229		
0	1648	~	3210	mcd	I _F =20mA
Р	2373	~	4623		
Q	3417	~	(6657)		

(Note 1) Tolerance:±15%

In regard to luminous intensity, the following ranking shall be carried out.

However the quantity of each rank shall not be pre scribed.

In case of the distribution of the luminous intensity shift to high, at that point new upper rank is prescribed and lower rank is delete.

6-3.Dominant wavelength rank (Note 2)

(Ta=25℃)

Rank	Domi	Dominant wavelength		Unit	Condition
0	598.5	~	602.0		
Р	601.0	~	604.5		
Q	603.5	~	607.0	nm	I _F =20mA
R	606.0	~	609.5		
S	608.5	~	612.0		

(Note 2) The condition of measurement: The measurement of the light emission from the front side of lamp.

This rank value is the setting value of when that classifies it the rank and be not a guarantee value.

Also I shall not ask the delivery ratio of each rank.

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6-4. Environment

- 6-4-1. Ozonosphere destructive chemicals.
 - (1) The device doesn't contain following substance.
 - (2) The device doesn't have a production line whose process requires following substance. Restricted part: CFCs,halones, CCl₄, Trichloroethane (Methychloroform)

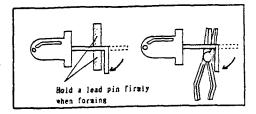
6-4-2. Bromic non-burning materials

The device doesn't contain bromic non-burning materials(PBBOs,PBBs)

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7. Precautions for use

7-1. Lead forming method Avoid forming a lead pin with the lead pin base as a fulcrum: be sure to hold a lead pin firmly when forming. Lead pins should be formed before soldering.

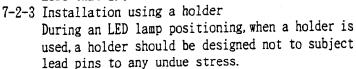


7-2. Notice of installation

7-2-1 installation on a PWB

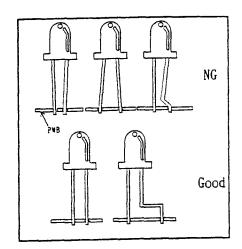
When mounting an LED lamp on a PWB, do not apply physical stress to the lead pins.

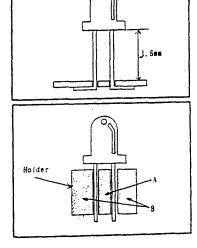
- The lead pin pitch should match the PWB pin-hole pitch: absolutely avoid widening or narrowing the lead pins.
- When positioning an LED lamp, basically employ an LED with tie-bar cut or use a spacer.
- 7-2-2 When an LED 1 is mounted directly on a PWB If the bottom face of an LED lamp is mounted directly on single-sided PWB, the base of the lead pins may be subjected to physical stress due to PWB warp, cutting or clinching of lead pins. Prior to use, be sure to check that no disconnection inside of the resin or damage to resin etc., is found. When an LED lamp is mounted on a double-sided PWB, the heat during soldering affects the resin; therefore, keep the LED lamp more that 1.6mm afloat above the PWB.

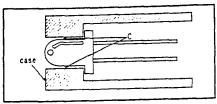


- (Note)Pay attention to the thermal expansion coefficient of the material used for the holder. Since the holder expands and contracts due to preheat and soldering heat, mechanical stress may be applied to the lead pins, resulting in disconnection.
- 7-2-4 Installation to the case

 Do not fix part C with adhesives when fixed to the case as shown in Figure A hole of the case should be designed not to subject the inside of resin to any undue stress.







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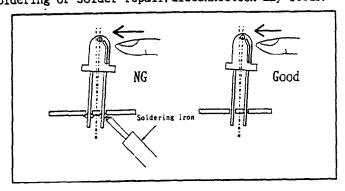
7-3. Soldering Conditions

Solder the lead pins under the following conditions

Type of Soldering	Conditions		
1. Manual soldering	295℃±5℃, within 3 seconds		
2. Wave soldering	260℃±5℃, within 5 seconds		
3. Auto soldering	Preheating 70°C to 80°C, within 30 seconds Soldering 245°C±5°C, within 5 seconds		

(Note) Avoid dipping resin into soldering bath.

Avoid applying stress to lead pins while they are heated. For example, when the LED lamp is moved with the heat applied to the lead pins during manual soldering or solder repair, disconnection may occur.



7-4. For cleaning

- (1) Solvent cleaning: Solvent temperature 45°C or less Immersion for 3 min or less
- (2) Ultrasonic cleaning: The effect to device by ultrasonic cleaning differs by cleaning bath size, ultrasonic power output, cleaning time, PWB size or device mounting condition etc. Please test it in actual using condition and confirm that doesn't occur any defect before starting the ultrasonic cleaning.
- (3) Applicable solvent: Ethyl alcohol, Methyl alcohol, Isopropyl alcohol

In case when the other solvent is used, there are cases that the packaging resin is eroded. Please use the other solvent after thorough confirmation is performed in actual using condition.